74AUP1G58

Low-power configurable multiple function gate

Rev. 10 — 24 July 2023

Product data sheet

1. General description

The 74AUP1G58 is a configurable multiple function gate with Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to V_{CC} or GND. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- · Latch-up performance exceeds 100 mA per JESD 78 Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | | | |
|-------------|-------------------|--------|--|-----------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| 74AUP1G58GW | -40 °C to +125 °C | TSSOP6 | plastic thin shrink small outline package; 6 leads; body width 1.25 mm | SOT363-2 | | | | | |
| 74AUP1G58GM | -40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm | SOT886 | | | | | |
| 74AUP1G58GN | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm | SOT1115 | | | | | |
| 74AUP1G58GS | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm | SOT1202 | | | | | |
| 74AUP1G58GX | -40 °C to +125 °C | X2SON6 | plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 × 0.8 × 0.32 mm | SOT1255-2 | | | | | |



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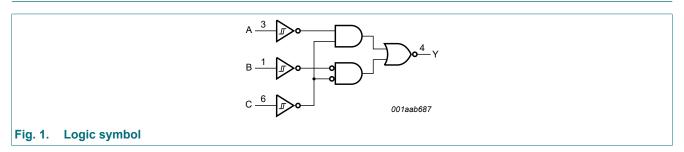
4. Marking

Table 2. Marking

| Type number | Marking code [1] |
|-------------|------------------|
| 74AUP1G58GW | аК |
| 74AUP1G58GM | аК |
| 74AUP1G58GN | аК |
| 74AUP1G58GS | аК |
| 74AUP1G58GX | аК |

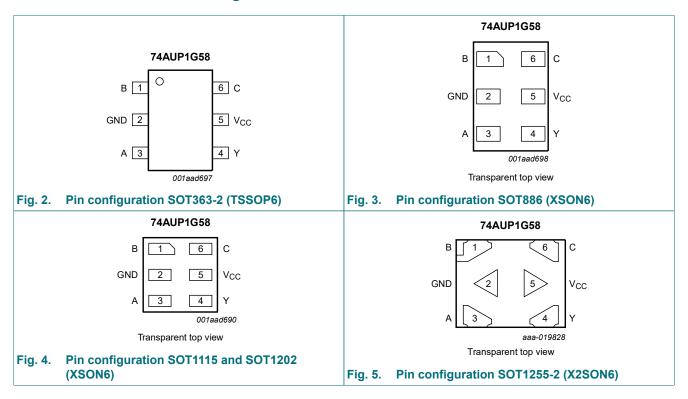
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



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6.2. Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|----------------|
| В | 1 | data input |
| GND | 2 | ground (0 V) |
| Α | 3 | data input |
| Υ | 4 | data output |
| V _{CC} | 5 | supply voltage |
| С | 6 | data input |

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

| Input | Output | | |
|-------|--------|---|---|
| С | В | A | Υ |
| L | L | L | L |
| L | L | Н | Н |
| L | Н | L | L |
| L | Н | Н | Н |
| Н | L | L | Н |
| Н | L | Н | Н |
| Н | Н | L | L |
| Н | Н | Н | L |

7.1. Logic configurations

Table 5. Function selection table

| Logic function | Figure |
|--|-----------------------|
| 2-input NAND | see Fig. 6 |
| 2-input NAND with both inputs inverted | see Fig. 9 |
| 2-input AND with inverted input | see Fig. 7 and Fig. 8 |
| 2-input NOR with inverted input | see Fig. 7 and Fig. 8 |
| 2-input OR | see Fig. 9 |
| 2-input OR with both inputs inverted | see Fig. 6 |
| 2-input XOR | see Fig. 10 |
| Buffer | see Fig. 11 |
| Inverter | see Fig. 12 |

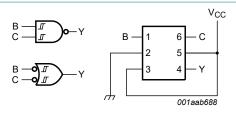


Fig. 6. 2-input NAND gate or 2-input OR with both inputs inverted

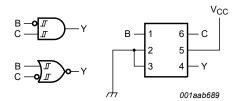


Fig. 7. 2-input AND gate with inverted B input or 2-input NOR gate with inverted C input

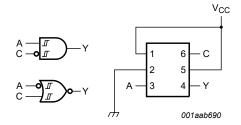


Fig. 8. 2-input AND gate with inverted C input or 2-input NOR gate with inverted A input

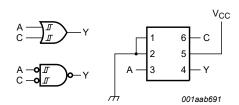


Fig. 9. 2-input OR gate or 2-input NAND gate with both inputs inverted

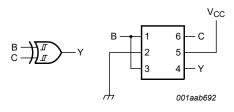


Fig. 10. 2-input XOR gate

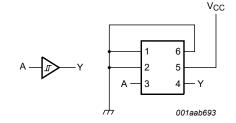


Fig. 11. Buffer

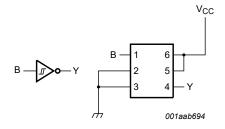


Fig. 12. Inverter

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8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|---|-----|------|------|------|
| V _{CC} | supply voltage | | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V _I < 0 V | | -50 | - | mA |
| VI | input voltage | | [1] | -0.5 | +4.6 | V |
| lok | output clamping current | V _O < 0 V | | -50 | - | mA |
| Vo | output voltage | Active mode and Power-down mode | [1] | -0.5 | +4.6 | V |
| Io | output current | V _O = 0 V to V _{CC} | | - | ±20 | mA |
| I _{CC} | supply current | | | - | 50 | mA |
| I _{GND} | ground current | | | -50 | - | mA |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +125 °C | [2] | - | 250 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1255-2 (X2SON6) package: Ptot derates linearly with 3.3 mW/K above 75 °C.

9. Recommended operating conditions

Table 7. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------|--|-----|-----------------|------|
| V_{CC} | supply voltage | | 0.8 | 3.6 | V |
| VI | input voltage | | 0 | 3.6 | V |
| Vo | output voltage | Active mode | 0 | V _{CC} | V |
| | | Power-down mode; V _{CC} = 0 V | 0 | 3.6 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |

^[2] For SOT363-2 (TSSOP6) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

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10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|---|------------------------|-----|-----------------------|------|
| T _{amb} = 2 | 5 °C | | | | 1 | |
| V _{OH} | HIGH-level output | $V_I = V_{T+}$ or V_{T-} | | | | |
| | voltage | I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.75 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.11 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.32 | - | - | V |
| | | I_{O} = -2.3 mA; V_{CC} = 2.3 V | 2.05 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.9 | - | - | V |
| | | I_{O} = -2.7 mA; V_{CC} = 3.0 V | 2.72 | - | - | V |
| | | I_{O} = -4.0 mA; V_{CC} = 3.0 V | = 3.0 V 2.6 - | - | V | |
| V _{OL} | LOW-level output | $V_I = V_{T+}$ or V_{T-} | | | | |
| | voltage | I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V | | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.31 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.31 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.31 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.44 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.31 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.44 | V |
| l _l | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.1 | μΑ |
| I _{OFF} | power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V | - | - | ±0.2 | μΑ |
| Δl _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.2 | μΑ |
| I _{CC} | supply current | V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.5 | μΑ |
| ΔI _{CC} | additional supply current | $V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ | - | - | 40 | μA |
| Cı | input capacitance | V_I = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V | - | 1.1 | - | pF |
| Co | output capacitance | $V_O = GND; V_{CC} = 0 V$ | - | 1.8 | - | pF |

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|---|-----------------------|-----|-----------------------|------|
| T _{amb} = - | 40 °C to +85 °C | | | | | |
| V _{OH} | HIGH-level output | $V_I = V_{T+}$ or V_{T-} | | | | |
| | voltage | I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.7 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.03 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.30 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.97 | - | - | V |
| | | I_{O} = -3.1 mA; V_{CC} = 2.3 V | 1.85 | - | - | V |
| | | I_{O} = -2.7 mA; V_{CC} = 3.0 V | 2.67 | - | - | V |
| | | I_{O} = -4.0 mA; V_{CC} = 3.0 V | 2.55 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+} \text{ or } V_{T-}$ | | | | |
| | | $I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.37 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.35 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.33 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.45 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.33 | V |
| | | I_{O} = 4.0 mA; V_{CC} = 3.0 V | - | - | 0.45 | V |
| l _l | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.5 | μΑ |
| I _{OFF} | power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V | - | - | ±0.5 | μΑ |
| Δl _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.6 | μΑ |
| I _{CC} | supply current | V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.9 | μA |
| Δl _{CC} | additional supply current | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ | - | - | 50 | μΑ |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|---|------------------------|-----|------------------------|------|
| T _{amb} = - | 40 °C to +125 °C | | | | | |
| V _{OH} | HIGH-level output | $V_I = V_{T+}$ or V_{T-} | | | | |
| | voltage | I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V | V _{CC} - 0.11 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.6 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 0.93 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.17 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.77 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.67 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.40 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.30 | - | - | V |
| V _{OL} | LOW-level output | $V_I = V_{T+}$ or V_{T-} | | | | |
| | voltage | I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.11 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.33 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.41 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.39 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.36 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.50 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.36 | V |
| | | I_{O} = 4.0 mA; V_{CC} = 3.0 V | - | - | 0.50 | V |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.75 | μΑ |
| l _{OFF} | power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V | - | - | ±0.75 | μΑ |
| Δl _{OFF} | additional power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V | - | - | ±0.75 | μΑ |
| I _{CC} | supply current | V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 1.4 | μΑ |
| Δl _{CC} | additional supply current | $V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ | - | - | 75 | μΑ |

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 14.

| Symbol | Parameter | Conditions | 25 °C | | -40 °C to +85 °C | | | | Unit | |
|-----------------|-------------|------------------------------------|-------|---------|---------------------|-----|------|-----|------|----|
| | | | Min | Typ [1] | Max | Min | Max | Min | Max | |
| $C_L = 5 p$ | F | | | | | | | | | |
| t _{pd} | propagation | A, B and C to Y; see Fig. 13 [2] | | | | | | | | |
| | delay | V _{CC} = 0.8 V | - | 22.8 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.8 | 6.6 | 12.9 | 2.6 | 13.1 | 2.6 | 13.3 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.4 | 4.8 | 7.6 | 2.4 | 8.3 | 2.4 | 8.6 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 2.1 | 4.0 | 6.3 | 2.0 | 6.9 | 2.0 | 7.3 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 2.0 | 3.2 | 4.6 | 1.8 | 5.1 | 1.8 | 5.4 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.9 | 2.9 | 3.9 | 1.6 | 4.2 | 1.6 | 4.4 | ns |

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| Symbol | Parameter | rameter Conditions | | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|----------------------|-----------------|---|-----|---------|------|---------------------|------|----------------------|------|------|
| | | | Min | Typ [1] | Max | Min | Max | Min | Max | |
| C _L = 10 | pF | | | | | | | | | |
| t _{pd} | propagation | A, B and C to Y; see <u>Fig. 13</u> [2] | | | | | | | | |
| | delay | V _{CC} = 0.8 V | - | 26.4 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 3.2 | 7.4 | 14.5 | 3.0 | 14.9 | 3.0 | 15.2 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.7 | 5.4 | 8.7 | 2.7 | 9.4 | 2.7 | 9.8 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 2.5 | 4.5 | 7.1 | 2.3 | 7.9 | 2.3 | 8.3 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 2.4 | 3.8 | 5.3 | 2.2 | 5.9 | 2.2 | 6.2 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.3 | 3.5 | 4.6 | 1.9 | 4.9 | 1.9 | 5.1 | ns |
| C _L = 15 | pF | | | • | | ' | ' | | ' | ' |
| t _{pd} | propagation | A, B and C to Y; see <u>Fig. 13</u> [2] | | | | | | | | |
| | delay | V _{CC} = 0.8 V | - | 29.9 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 3.6 | 8.3 | 16.1 | 3.3 | 16.7 | 3.3 | 17.0 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 3.0 | 5.9 | 9.7 | 3.0 | 10.5 | 3.0 | 11.0 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 2.8 | 5.0 | 7.9 | 2.5 | 8.7 | 2.5 | 9.2 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 2.7 | 4.2 | 5.9 | 2.5 | 6.6 | 2.5 | 6.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.5 | 3.9 | 5.2 | 2.2 | 5.5 | 2.2 | 5.8 | ns |
| C _L = 30 | pF | | | , | | | | | | |
| t _{pd} | propagation | A, B and C to Y; see <u>Fig. 13</u> [2] | | | | | | | | |
| | delay | V _{CC} = 0.8 V | - | 38.0 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 4.5 | 10.5 | 20.8 | 4.1 | 21.9 | 4.1 | 24.1 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 3.8 | 7.5 | 12.2 | 3.8 | 13.5 | 3.8 | 14.1 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 3.4 | 6.3 | 10.0 | 3.1 | 11.2 | 3.1 | 11.9 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 3.4 | 5.3 | 7.5 | 3.1 | 8.4 | 3.1 | 8.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 3.3 | 5.0 | 6.6 | 2.9 | 7.1 | 2.9 | 7.4 | ns |
| C _L = 5 p | F, 10 pF, 15 pF | and 30 pF | | ' | | | | | | |
| C _{PD} | power | $f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3][4] | | | | | | | | |
| | dissipation | V _{CC} = 0.8 V | - | 2.7 | - | - | - | - | - | pF |
| | capacitance | V _{CC} = 1.1 V to 1.3 V | - | 2.8 | - | - | - | - | - | pF |
| | | V _{CC} = 1.4 V to 1.6 V | - | 3.0 | - | - | - | - | - | pF |
| | | V _{CC} = 1.65 V to 1.95 V | - | 3.2 | - | - | - | - | - | pF |
| | | V _{CC} = 2.3 V to 2.7 V | - | 3.8 | - | - | - | - | - | pF |
| | | V _{CC} = 3.0 V to 3.6 V | - | 4.4 | - | - | - | - | - | pF |

All typical values are measured at nominal V_{CC}.

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma (C_L \times V_{CC}^{\ 2} \times f_o) = \text{sum of the outputs}.$

^[1] [2]

 ^[2] t_{pd} is the same as t_{PLH} and t_{PHL}.
 [3] All specified values are the average typical values over all stated loads.

^[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

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11.1. Waveforms and test circuit

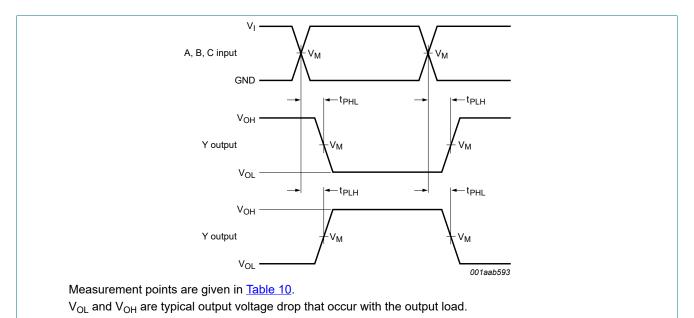
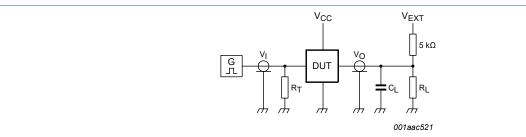


Table 10. Measurement points

| Supply voltage | Output | Input | | | | |
|-----------------|-----------------------|-----------------------|-----------------|-------------|--|--|
| V _{CC} | V _M | V _M | VI | $t_r = t_f$ | | |
| 0.8 V to 3.6 V | 0.5 × V _{CC} | 0.5 × V _{CC} | V _{CC} | ≤ 3.0 ns | | |



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 13. Input A, B and C to output Y propagation delay times

Fig. 14. Test circuit for measuring switching times

Table 11. Test data

| Supply voltage | Load | V _{EXT} | | | |
|-----------------|------------------------------|--------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| V _{CC} | CL | R _L [1] | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open | GND | 2 × V _{CC} |

[1] For measuring enable and disable times R_L = 5 k Ω .

For measuring propagation delays, setup and hold times and pulse width R_L = 1 $M\Omega$.

Product data sheet

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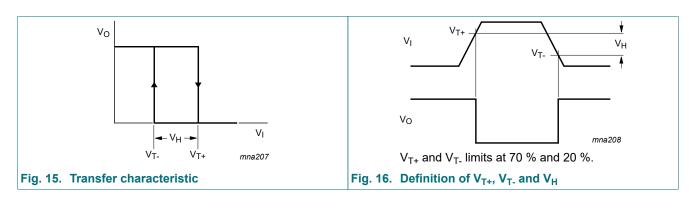
12. Transfer characteristics

Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 14.

| Symbol Parameter | | Conditions | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit | |
|------------------|-----------------------------------|--|-------|------|---------------------|------|----------------------|------|------|---|
| | | Min | Тур | Max | Min | Max | Min | Max | | |
| V _{T+} | positive-going | see Fig. 15 and Fig. 16 | | | | | | | | |
| | threshold voltage | V _{CC} = 0.8 V | 0.30 | - | 0.60 | 0.30 | 0.60 | 0.30 | 0.62 | V |
| | Voltage | V _{CC} = 1.1 V | 0.53 | - | 0.90 | 0.53 | 0.90 | 0.53 | 0.92 | V |
| | | V _{CC} = 1.4 V | 0.74 | - | 1.11 | 0.74 | 1.11 | 0.74 | 1.13 | V |
| | | V _{CC} = 1.65 V | 0.91 | - | 1.29 | 0.91 | 1.29 | 0.91 | 1.31 | V |
| | | V _{CC} = 2.3 V | 1.37 | - | 1.77 | 1.37 | 1.77 | 1.37 | 1.80 | V |
| | | V _{CC} = 3.0 V | 1.88 | - | 2.29 | 1.88 | 2.29 | 1.88 | 2.32 | V |
| V_{T-} | threshold | see Fig. 15 and Fig. 16 | | | | | | | | |
| | | V _{CC} = 0.8 V | 0.10 | - | 0.60 | 0.10 | 0.60 | 0.10 | 0.60 | V |
| | voltage | V _{CC} = 1.1 V | 0.26 | - | 0.65 | 0.26 | 0.65 | 0.26 | 0.65 | V |
| | | V _{CC} = 1.4 V | 0.39 | - | 0.75 | 0.39 | 0.75 | 0.39 | 0.75 | V |
| | | V _{CC} = 1.65 V | 0.47 | - | 0.84 | 0.47 | 0.84 | 0.47 | 0.84 | V |
| | V _{CC} = 2.3 V | 0.69 | - | 1.04 | 0.69 | 1.04 | 0.69 | 1.04 | V | |
| | V _{CC} = 3.0 V | 0.88 | - | 1.24 | 0.88 | 1.24 | 0.88 | 1.24 | V | |
| V _H | V _H hysteresis voltage | (V _{T+} - V _{T-}); see <u>Fig. 15</u> , <u>Fig. 16</u> , <u>Fig. 17</u> and <u>Fig. 18</u> | | | | | | | | |
| | V _{CC} = 0.8 V | 0.07 | - | 0.50 | 0.07 | 0.50 | 0.07 | 0.50 | V | |
| | V _{CC} = 1.1 V | 0.08 | - | 0.46 | 0.08 | 0.46 | 0.08 | 0.46 | V | |
| | V _{CC} = 1.4 V | 0.18 | - | 0.56 | 0.18 | 0.56 | 0.18 | 0.56 | V | |
| | | V _{CC} = 1.65 V | 0.27 | - | 0.66 | 0.27 | 0.66 | 0.27 | 0.66 | V |
| | | V _{CC} = 2.3 V | 0.53 | - | 0.92 | 0.53 | 0.92 | 0.53 | 0.92 | V |
| | | V _{CC} = 3.0 V | 0.79 | - | 1.31 | 0.79 | 1.31 | 0.79 | 1.31 | V |

12.1. Waveforms transfer characteristics



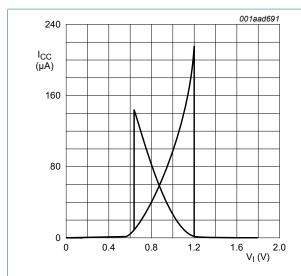


Fig. 17. Typical transfer characteristics; $V_{CC} = 1.8 \text{ V}$

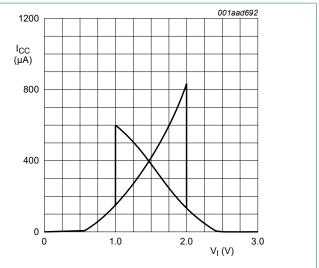


Fig. 18. Typical transfer characteristics; V_{CC} = 3.0 V

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13. Package outline

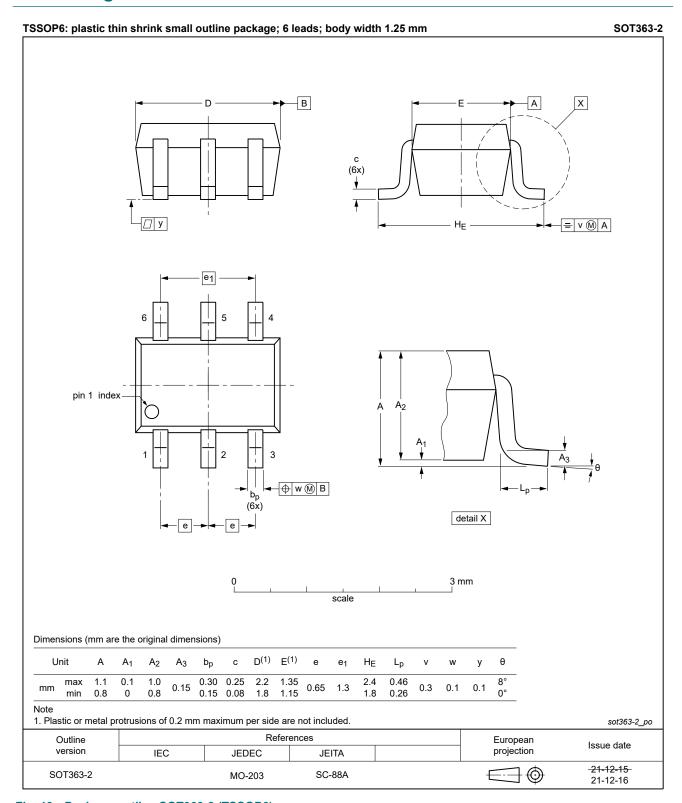


Fig. 19. Package outline SOT363-2 (TSSOP6)

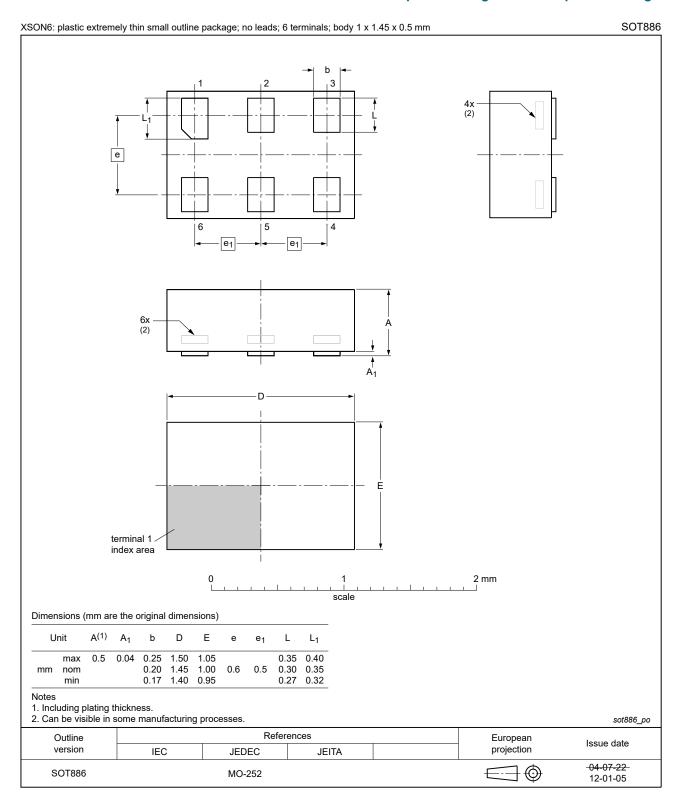


Fig. 20. Package outline SOT886 (XSON6)

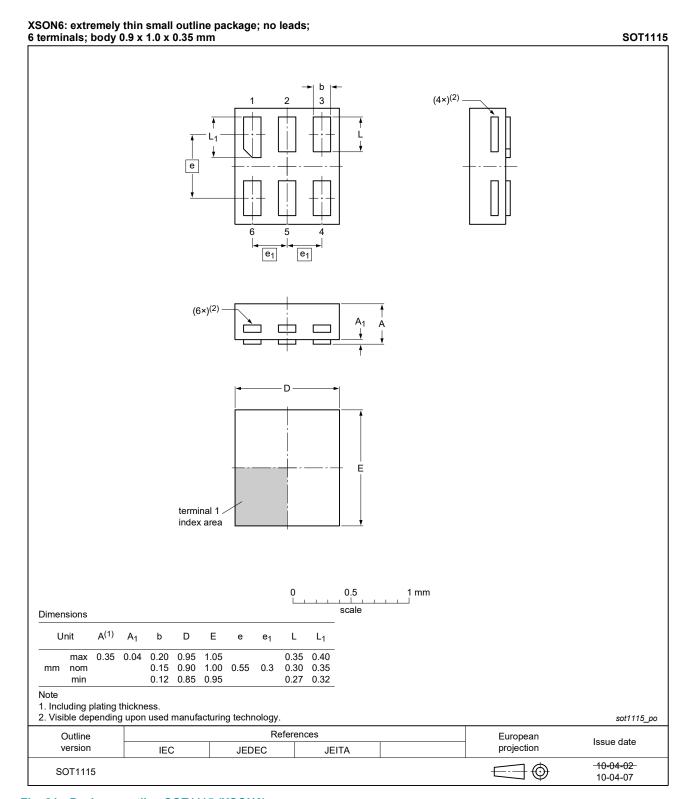


Fig. 21. Package outline SOT1115 (XSON6)

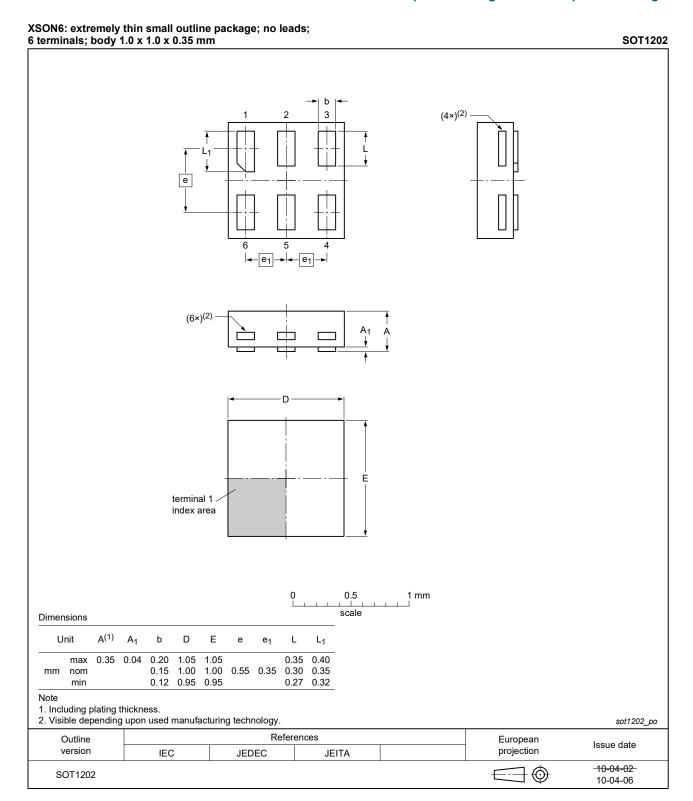


Fig. 22. Package outline SOT1202 (XSON6)

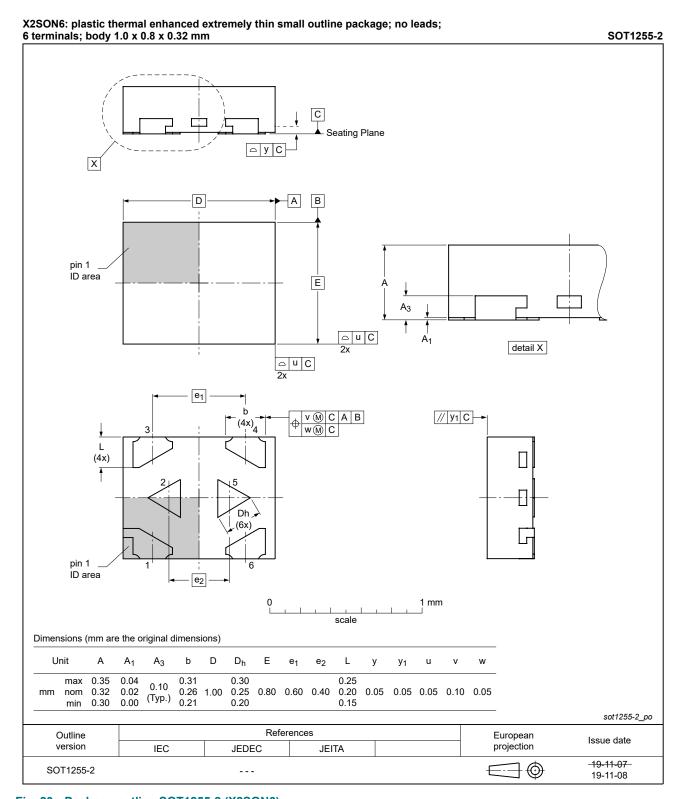


Fig. 23. Package outline SOT1255-2 (X2SON6)

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14. Abbreviations

Table 13. Abbreviations

| Acronym | Description |
|---------|-------------------------|
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |

15. Revision history

Table 14. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | | | |
|----------------|---|--|----------------|---------------|--|--|--|--|
| 74AUP1G58 v.10 | 20230724 | Product data sheet | - | 74AUP1G58 v.9 | | | | |
| Modifications: | Section 2: E | Section 2: ESD specification updated according to the latest JEDEC standard. | | | | | | |
| 74AUP1G58 v.9 | 20220124 | Product data sheet | - | 74AUP1G58 v.8 | | | | |
| Modifications: | • SOT363 (So | C-88) package changed to | SOT363-2 (TSSC | DP6) package. | | | | |
| 74AUP1G58 v.8 | 20210713 | Product data sheet | - | 74AUP1G58 v.7 | | | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. SOT1255 (X2SON6) package changed to SOT1255-2 (X2SON6) package. Type number 74AUP1G58GF (SOT891/XSON6) removed. Section 1 and Section 2 updated. Table 6: Derating values for Ptot total power dissipation updated. | | | | | | | |
| 74AUP1G58 v.7 | 20150917 | Product data sheet | - | 74AUP1G58 v.6 | | | | |
| Modifications: | Added type | Added type number 74AUP1G58GX (SOT1255/X2SON6). | | | | | | |
| 74AUP1G58 v.6 | 20120815 | Product data sheet | - | 74AUP1G58 v.5 | | | | |
| Modifications: | Package outline drawing of SOT886 (Fig. 20) modified. | | | | | | | |
| 74AUP1G58 v.5 | 20111129 | Product data sheet | - | 74AUP1G58 v.4 | | | | |
| 74AUP1G58 v.4 | 20101011 | Product data sheet | - | 74AUP1G58 v.3 | | | | |
| 74AUP1G58 v.3 | 20090622 | Product data sheet | - | 74AUP1G58 v.2 | | | | |
| 74AUP1G58 v.2 | 20090326 | Product data sheet | - | 74AUP1G58 v.1 | | | | |
| | + | | <u> </u> | | | | | |

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|--------------------------------|-----------------------|---|
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| Product [short] data sheet | Production | This document contains the product specification. |

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